

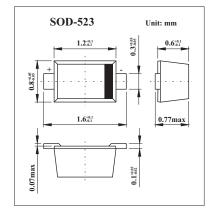
Diodes

# **Fast Switching Speed Diodes**

## KMP1340-079

#### Features

- Designed for Fast Speed Wireless Switch Applications
- Multiple Package Configurations
- Designed for High Volume Wireless Applications
- Ls = 0.7 nH



### ■ Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	Ratings	Units	
continuous reverse voltage	VR	50	V	
total power dissipation	PD	250	mW	
Junction temperature	Tj	-65 to +150	°C	
Storage temperature	Tstg	-65 to +150	Ĉ	

### ■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	Vf	IF=10mA		0.85		V
Reverse current	lr	VR=50V	VR=50V		10	μA
Capacitance	Ст	f= 1 MHz, V = 5 V		0.22	0.30	pF
Resistance	Rs	f = 100 MHz, I = 1 mA		1.8		Ω
		f = 100 MHz, I = 5 mA		1.1	2.0	Ω
		f= 100 MHz, I = 10 mA		0.9	1.2	Ω
Carrier Lifetime	Tı	IF = 10 mA		100		nS
I Region Width				0.80		μm

#### Marking

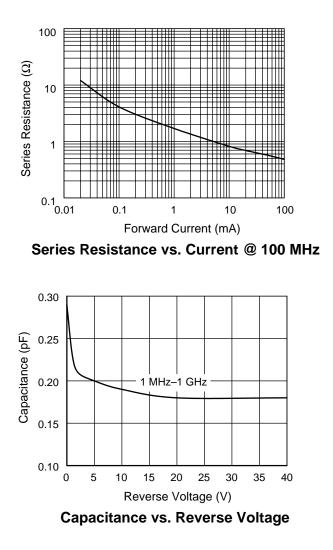
Marking K5

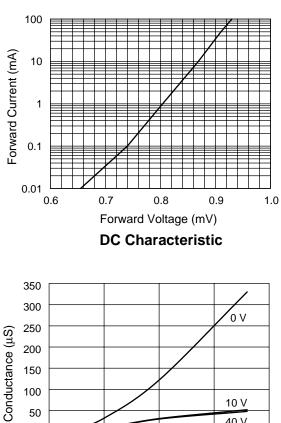


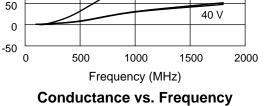
SMD Type

Diodes











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